



P-Channel 40-V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A) ^b			
- 40	0.082 at V _{GS} = - 10 V	- 3.0			
	0.130 at V _{GS} = - 4.5 V	- 2.4			

FEATURES

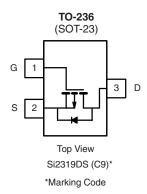
- Halogen-free According to IEC 61249-2-21 Available
- TrenchFET® Power MOSFET

RoHS COMPLIANT HALOGEN

FREE

APPLICATIONS

· Load Switch



Ordering Information: Si2319DS-T1-E3 (Lead (Pb)-free)

Si2319DS-T1-GE3 (Lead (Pb)-free and Halogen-free)

Parameter		Symbol	5 s	Steady State	Unit
Drain-Source Voltage		V_{DS}	- 40		V
Gate-Source Voltage		V_{GS}	± 20		
Ocation of David Comment (T., 150 cOvb.	T _A = 25 °C	I _D	- 3.0	- 2.3	
Continuous Drain Current (T _J = 150 °C) ^b	T _A = 70 °C		- 2.4	- 1.85	
Pulsed Drain Current ^a		I _{DM}	- 12		Α
Continuous Source Current (Diode Conduction) ^b		I _S	- 1.0	- 0.62	
	T _A = 25 °C	P _D	1.25	0.75	W
Power Dissipation ^b	T _A = 70 °C		0.8	0.48	VV
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Typical	Maximum	Unit		
Maximum Junction-to-Ambient ^b	R _{thJA}	75	100			
Maximum Junction-to-Ambient ^c	' 'thJA	120	166	°C/W		
Maximum Junction-to-Foot (Drain)	R _{thJF}	40	50			

Notes:

- a. Pulse width limited by maximum junction temperature.
- b. Surface mounted on FR4 board, $t \le 5$ s.
- c. Surface Mounted on FR4 board.

For Spice model information via the worldwide web: $\underline{www.vishay.com/www/product/spice.htm}.$

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			Limits				
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static				•			
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$	- 40			V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 1		- 3.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zava Cata Valtaga Dvain Current	1	V _{DS} = - 40 V, V _{GS} = 0 V	-1		- 1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -40 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			- 10	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \le -5 \text{ V}, V_{GS} = -10 \text{ V}$	- 6			Α	
		$V_{GS} = -10 \text{ V}, I_D = -3.0 \text{ A}$		0.065	0.082		
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -2.4 \text{ A}$	0.100 0.		0.130	Ω	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = -5 \text{ V}, I_D = -3.0 \text{ A}$		7.0		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 1.25 A, V _{GS} = 0 V		- 0.8	- 1.2	V	
Dynamic ^b							
Total Gate Charge	Q_g	V 20 V V 40 V		11.3	17	nC	
Gate-Source Charge	Q_{gs}	$V_{DS} = -20 \text{ V}, V_{GS} = -10 \text{ V}$ $I_{D} \cong -3 \text{ A}$		1.7			
Gate-Drain Charge	Q_{gd}	1D = - 2 V		3.3		-	
Input Capacitance	C _{iss}			470		pF	
Output Capacitance	C _{oss}	$V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		85			
Reverse Transfer Capacitance	C _{rss}			65			
Switching ^c	<u>'</u>		•				
Turn On Time	t _{d(on)}			7	15	- ns	
Turn-On Time	t _r	$V_{DD} = -20 \text{ V}, R_L = 20 \Omega$		15	25		
Town Of Time	t _{d(off)}	$I_D \cong$ - 1.0 A, $V_{GEN} =$ - 4.5 V $R_a = 6 \Omega$		25	40		
Turn-Off Time		$t_f = 0.52$		25	40		

Notes:

- a. Pulse test: PW \leq 300 μs duty cycle \leq 2 %.
- b. For design aid only, not subject to production testing.
- c. Switching time is essentially independent of operating temperature.

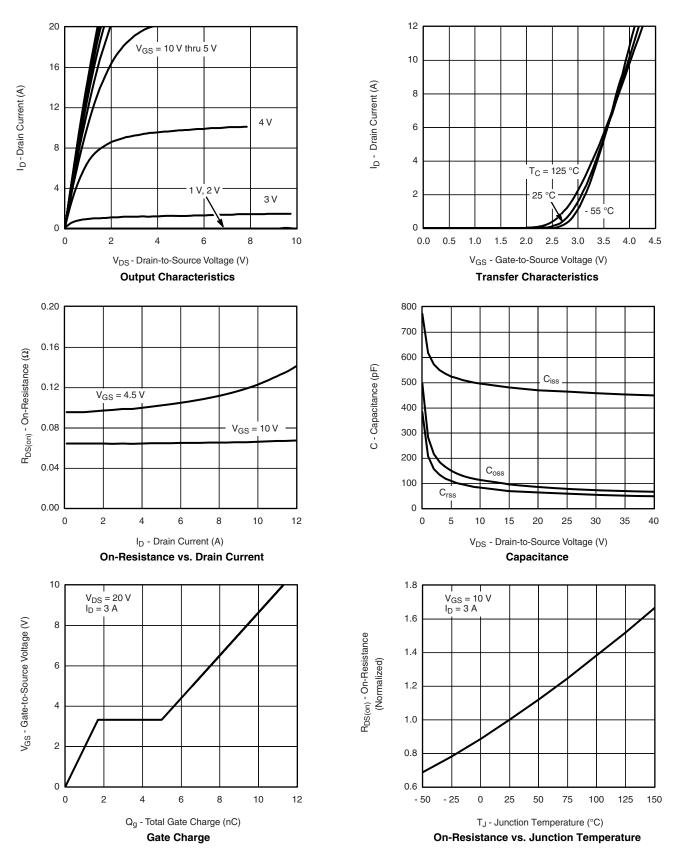
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.







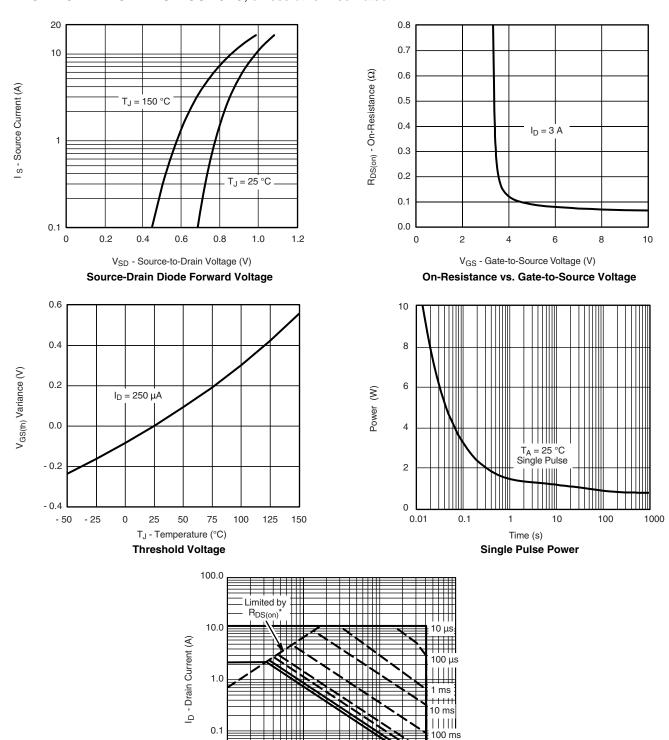
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



T_A = 25 °C Single Pulse

0.01 **L**

10 s, 1 s

100 s, DC

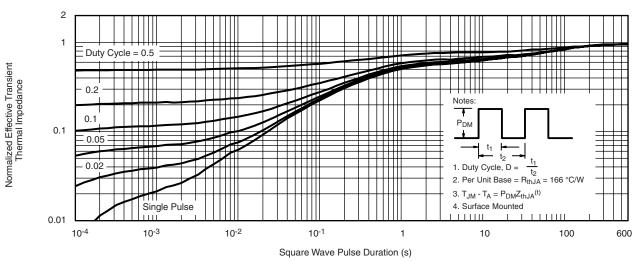
Safe Operating Area, Junction-to-Case

 $V_{\mbox{\footnotesize DS}}$ - Drain-to-Source Voltage (V)

^{*} V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

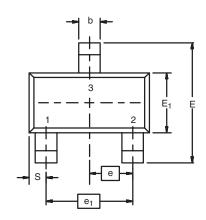


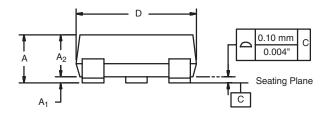
Normalized Thermal Transient Impedance, Junction-to-Ambient

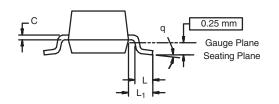
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SOT-23 (TO-236): 3-LEAD







Dim	MILLI	METERS	INCHES		
	Min	Max	Min	Max	
Α	0.89	1.12	0.035	0.044	
A ₁	0.01	0.10	0.0004	0.004	
A ₂	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E ₁	1.20	1.40	0.047	0.055	
е	0.9	0.95 BSC 0.		374 Ref	
e ₁	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024	
L ₁	0.64 Ref		0.025 Ref		
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	
FCN: S-03946-Rev K 09-	lul-01	•			

ECN: S-03946-Rev. K, 09-Jul-01

DWG: 5479

Document Number: 71196 www.vishay.com 09-Jul-01



RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE



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